



SBR12U45LH

12A SBR[®] SUPER BARRIER RECTIFIER POWERDI[®]5SP

Product Summary

V _{RRM} (V)	l _O (A)	V _{F(typ)} @ 125°C (V)	I _{R(MAX)} @ V _{RRM} (mA)
45	12	0.38	0.3

Description

The SBR12U45LH uses SBR patented technology that offers ultralow V_F to reduce forward power loss and improve efficiency. Encapsulated in the new PDI-5SP package with a 0.75mm low height profile and protruding leads for easy soldering, it is especially suited for use as a bypass diode in solar panels.

Applications

Solar Bypass Diode

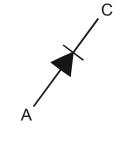
Features

- Designed as bypass diodes for solar panels
- Low profile height (0.75mm) and 9mm protruding leads, enabling the package to be integrated within the solar glass panel
- Selectively rated for 200°C maximum junction temperature for high thermal reliability and excellent high temperature stability
- Patented Super Barrier Rectifier technology
- Ultra low forward voltage drop to minimize forward power losses
- Very low reverse leakage to ensures maximum efficiency of solar panel
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: POWERDI[®]5SP
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.199 grams (approximate)





Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
SBR12U45LH-13	POWERDI5SP	3500 Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information

Notes:

SBR12U45 = Product Type Marking Code)'' = Manufacturers' Code Marking YYWWK = Date Code Marking YY = Last Two Digits of Year (ex: 11 for 2011) WW = Week Code (01 ~ 53) K = Factory Designator

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^{2.} See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.	·		
For capacitance load, derate current by 20%.			
Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	45	V
Average Rectified Output Current	lo	12	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	300	А

Thermal Characteristics

Chara	acteristic	Symbol	Value	Unit	
Typical Thermal Resistance Junc	tion to Ambient (Note 5)	R _{0JA}	66	°C/W	
Operating Temperature Range	V _R ≤ 80% V _{RRM}	т.	-65 to +150	°C	
	DC Forward Mode (Note 7)	١j	≤175	C C	
	DC Forward Mode (Note 8)		≤200		
Storage Temperature Range		T _{STG}	-65 to +175	С°	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
	Ň	—	0.40	0.48	V	I _F = 10A, T _J = +25°C
Forward Voltage Drop	VF	—	0.42	0.50		I _F = 12A, T _J = +25°C
		_	0.38	0.45		I _F = 12A, T _J = +125°C
		_	70	200		V _R = 40V, T _J = +25°C
Laskaga Current (Nota 6)		_	90	300		V _R = 45V, T _J = +25°C
Leakage Current (Note 6)	I _R	_	19	_		V _R = 45V, T _J = +125°C
		_	60	_	mΩ	V _R = 45V, T _J = +150°C

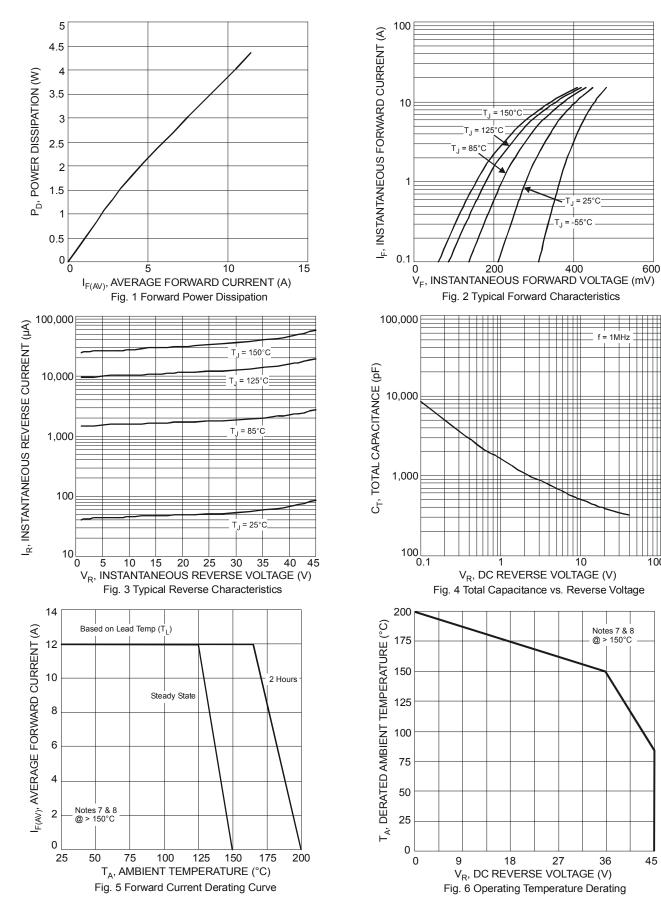
Notes: 5. FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com.pdf.

6. Short duration pulse test used to minimize self-heating effect.

Max junction temperature 175°C guaranteed for 2 hours at maximum output.
Max junction temperature 200°C guaranteed for 2 hours at maximum output.



SBR12U45LH



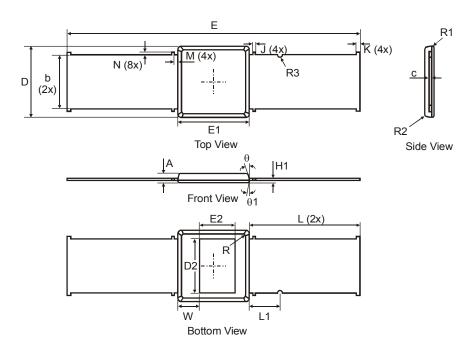
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Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI [®] 5SP							
	IVIII	-	Тур				
Α	-	0.75	0.736				
С	0.155	0.195	-				
b	4.30	4.50	4.40				
D	5.70	5.90	5.80				
D2	-	-	4.40				
E	23.6	24.0	23.8				
E1	5.70	5.90	5.80				
E2	-	-	2.90				
H1	0.19	0.21	0.20				
L	-	-	9.00				
L1	-	-	2.50				
w	1.63	1.97	1.80				
J	-	-	0.20				
к	-	-	0.30				
м	-	-	0.03				
Ν	0	0.20	-				
R	-	-	0.40				
R1	-	-	0.15				
R2	_	_	0.25				
R3	—	_	0.40				
θ	4°	12°	_				
θ2	0°	8°	-				
All I							



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